



MMDT3904

40V DUAL NPN SMALL SIGNAL TRANSISTOR IN SOT363

Features

- Epitaxial Planar Die Construction
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

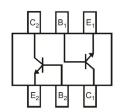
Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound,
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Finish. Solderable per MIL-STD-202, Method 208 (3)
- · Weight: 0.006 grams (approximate)

SOT363



Top View



Device Schematic Top View

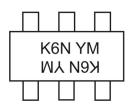
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
MMDT3904-7-F	K6N	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html.

Marking Information



K6N = Product Type Marking Code YM = Date Code Marking Y = Year (ex: X = 2010) M = Month (ex: 9 = September)

Date Code Key

Year	2010		2011	2012		2013	2014		2015	2016		2017
Code	X		Υ	Z		Α	В		С	D		Е
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	60	V
Collector-Emitter Voltage	V_{CEO}	40	V
Emitter-Base Voltage	V_{EBO}	6.0	V
Continuous Collector Current	Ic	200	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P_{D}	200	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ heta JA}$	625	°C/W
Operating and Storage and Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

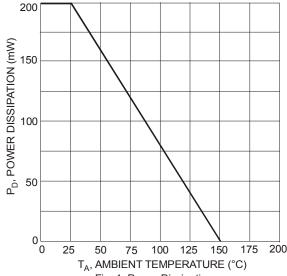
Characteristic	Symbol	Min	Max	Unit	Test Condition	
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV_{CBO}	60		V	$I_C = 100 \mu A, I_E = 0$	
Collector-Emitter Breakdown Voltage (Note 6)	BV _{CEO}	40		V	$I_C = 10.0 \text{mA}, I_B = 0$	
Emitter-Base Breakdown Voltage	BV_{EBO}	6.0	_	V	$I_E = 100 \mu A, I_C = 0$	
Collector-Base Cutoff Current	I _{CBO}		50	nA	V _{CB} = 50V	
Collector-Emitter Cutoff Current	I _{CEV}	_	50	nA	$V_{CE} = 40V, V_{BE(OFF)} = 3.0V$	
Collector-Emitter Cuton Current			50		V _{CE} = 40V, V _{BE(ON)} = 0.25V	
Emitter-Base Cutoff Current	I _{EBO}	_	50	nA	V _{EB} = 5V	
ON CHARACTERISTICS (Note 6)						
		40	_		$I_C = 100 \mu A$, $V_{CE} = 1.0 V$	
		70	_		$I_C = 1.0 \text{mA}, V_{CE} = 1.0 \text{V}$	
DC Current Gain	h _{FE}	100	300		$I_C = 10 \text{mA}, V_{CE} = 1.0 \text{V}$	
		60	_		$I_C = 50 \text{mA}, V_{CE} = 1.0 \text{V}$	
		30	_		$I_C = 100 \text{mA}, V_{CE} = 1.0 \text{V}$	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	_	0.20		$I_C = 10mA$, $I_B = 1.0mA$	
Concetor-Enniter Cataration Voltage	V CE(sat)		0.30		$I_C = 50 \text{mA}, I_B = 5.0 \text{mA}$	
Base-Emitter Saturation Voltage	V _{BE(sat)}	0.65	0.85	V	$I_C = 10 \text{mA}, I_B = 1.0 \text{mA}$	
· ·		—	0.95	V	$I_C = 50 \text{mA}, I_B = 5.0 \text{mA}$	
SMALL SIGNAL CHARACTERISTICS	1			1		
Output Capacitance	C _{obo}	_	4.0	pF	$V_{CB} = 5.0V, f = 1.0MHz, I_E = 0$	
Input Capacitance	C _{ibo}	_	8.0	pF	$V_{EB} = 0.5V$, $f = 1.0MHz$, $I_{C} = 0$	
Input Impedance	h _{ie}	1.0	10	kΩ		
Voltage Feedback Ratio		0.5	8.0	x 10 ⁻⁴	$V_{CE} = 10V, I_{C} = 1.0mA,$	
Small Signal Current Gain	h _{fe}	100	400	_	f = 1.0kHz	
Output Admittance	h _{oe}	1.0	40	μS		
Current Gain-Bandwidth Product	f⊤	300		MHz	V _{CE} = 20V, I _C = 10mA, f = 100MHz	
Noise Figure	NF		5.0	dB	$V_{CE} = 5.0V, I_C = 100\mu A,$	
Noise Figure			5.0	ав	$R_S = 1.0k\Omega$, $f = 1.0kHz$	
SWITCHING CHARACTERISTICS						
Delay Time	t _d	_	35	ns	$V_{CC} = 3.0V, I_C = 10mA,$	
Rise Time	tr		35	ns	$V_{BE(off)} = -0.5V$, $I_{B1} = 1.0mA$	
Storage Time	ts	_	200	ns	V _{CC} = 3.0V, I _C = 10mA,	
Fall Time	t _f	_	50	ns	$I_{B1} = I_{B2} = 1.0 \text{mA}$	

Notes:

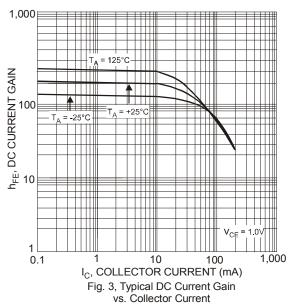
^{5.} For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

6. Short duration pulse test used to minimize self-heating effect.



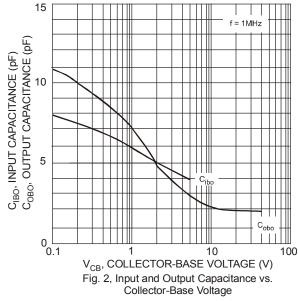


T_A, AMBIENT TEMPERATURE (°C) Fig. 1, Power Dissipation vs. Ambient Temperature (Total Device)



10 V_{BE(SAT)}, BASE-EMITTER (V) SATURATION VOLTAGE 0.1 <u></u> 1 10 100 I_C, COLLECTOR CURRENT (mA) 1,000

Fig. 5, Typical Base-Emitter Saturation Voltage vs. Collector Current



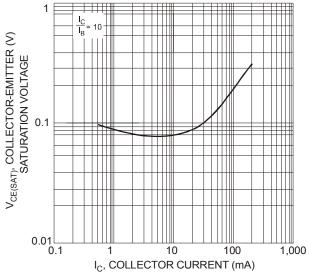
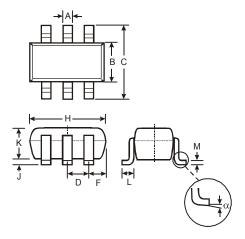


Fig. 4, Typical Collector-Emitter Saturation Voltage vs. Collector Current



Package Outline Dimensions

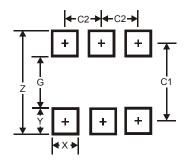
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT363							
Dim	Min	Max	Тур					
Α	0.10	0.30	0.25					
В	1.15	1.35	1.30					
C 2.00		2.20	2.10					
D	0.65 Typ							
F	0.40	0.45	0.425					
Н	1.80	2.20	2.15					
J	J 0		0.05					
K	0.90	1.00	1.00					
L	0.25	0.40	0.30					
М	0.10	0.22	0.11					
α	0°	8°	-					
All	All Dimensions in mm							

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.5
G	1.3
Х	0.42
Υ	0.6
C1	1.9
C2	0.65



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